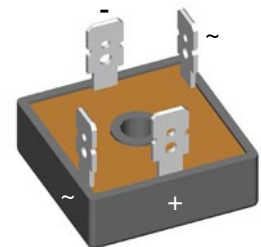
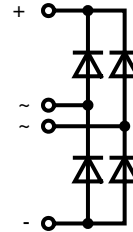


Three Phase Rectifier Bridge

$$I_{dAV} = 30 \text{ A}$$

$$V_{RRM} = 800-1800 \text{ V}$$

V_{RSM} V_{DSM} V	V_{RRM} V_{DRM} V	Type
800	800	VBO 36-08NO8
1200	1200	VBO 36-12NO8
1400	1400	VBO 36-14NO8
1600	1600	VBO 36-16NO8
1800	1800	VBO 36-18NO8



Symbol	Conditions	Maximum Ratings	
I_{dAV}	$T_C = 85^\circ\text{C}$, module	25	A
I_{dAVM}	$T_C = 62^\circ\text{C}$, module	30	A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz)	550	A
	$V_R = 0$; $t = 8.3 \text{ ms}$ (60 Hz)	600	A
	$T_{VJ} = T_{VJM}$; $t = 10 \text{ ms}$ (50 Hz)	500	A
	$V_R = 0$; $t = 8.3 \text{ ms}$ (60 Hz)	550	A
I^2t	$T_{VJ} = 45^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz)	1520	A ² s
	$V_R = 0$; $t = 8.3 \text{ ms}$ (60 Hz)	1520	A ² s
	$T_{VJ} = T_{VJM}$; $t = 10 \text{ ms}$ (50 Hz)	1250	A ² s
	$V_R = 0$; $t = 8.3 \text{ ms}$ (60 Hz)	1250	A ² s
T_{VJ}		-40...+150	°C
T_{VJM}		150	°C
T_{stg}		-40...+150	°C
V_{ISOL}	50/60 Hz, RMS $t = 1 \text{ min}$	2500	V~
	$I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$	3000	V~
M_d	Mounting torque (M5) (10-32 UNF)	2 ±10%	Nm
		18 ±10%	lb.in.
Weight	Typ.	22	g

Symbol	Conditions	Characteristic Values	
I_R	$V_R = V_{RRM}$ $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = T_{VJM}$	0.3	mA
		2.0	mA
V_F	$I_F = 150 \text{ A}$ $T_{VJ} = 25^\circ\text{C}$	1.7	V
V_{T0}	For power-loss calculations only	0.8	V
r_t		5.8	mΩ
R_{thJC}	per diode; 120° el.	6.20	K/W
	per module	1.55	K/W
R_{thCH}	per diode; 120° el.	7.40	K/W
	per module	1.85	K/W
d_s	Creeping distance on surface	12.7	mm
d_A	Creepage distance in air	9.4	mm
a	Max. allowable acceleration	50	m/s ²

Data according to IEC 60747 and refer to a single diode unless otherwise stated.

Features

- Package with ¼" fast-on terminals
- Isolation voltage 3000 V~
- Planar passivated chips
- Blocking voltage up to 1800 V
- Low forward voltage drop
- UL registered E 72873

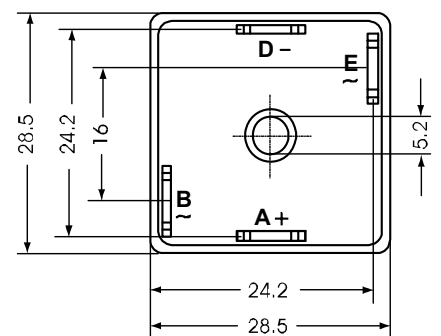
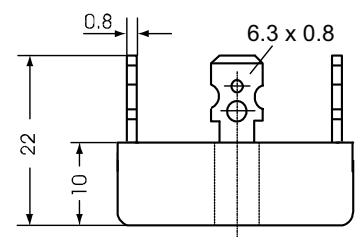
Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Advantages

- Easy to mount with one screw
- Space and weight savings
- Improved temperature & power cycling

Dimensions in mm (1 mm = 0.0394")



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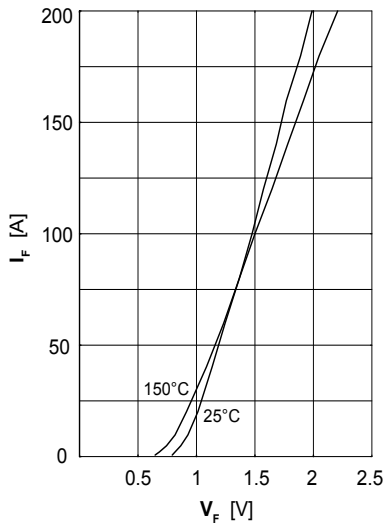


Fig. 1 Forward current versus voltage drop per diode

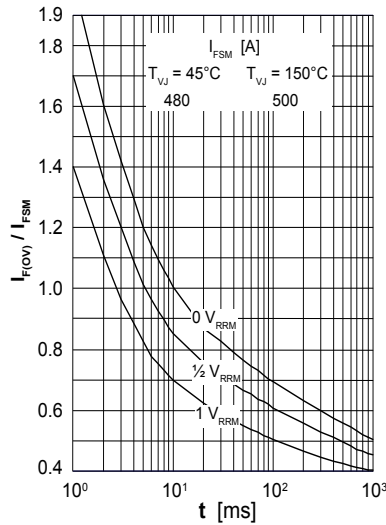


Fig. 2 Surge overload current per diode
 I_{FSM} : crest value, t : duration

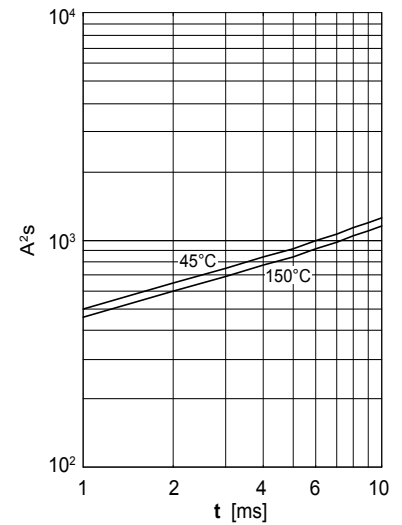


Fig. 3 I^2t versus time (1-10 ms)
per diode or thyristor

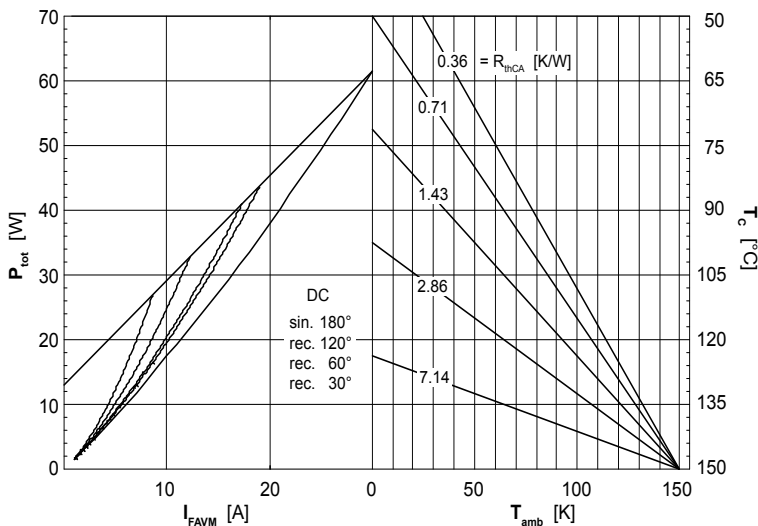


Fig. 4 Power dissipation vs. direct output current and ambient temperature

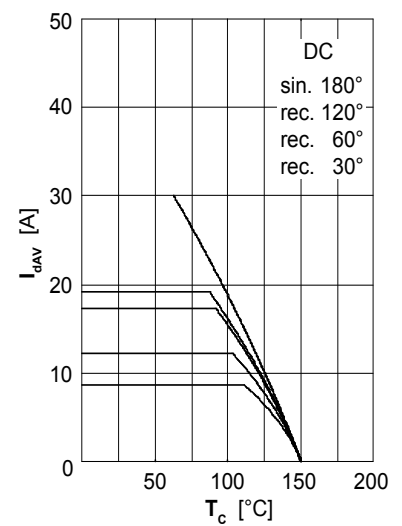


Fig. 5 Maximum forward current
at case temperature

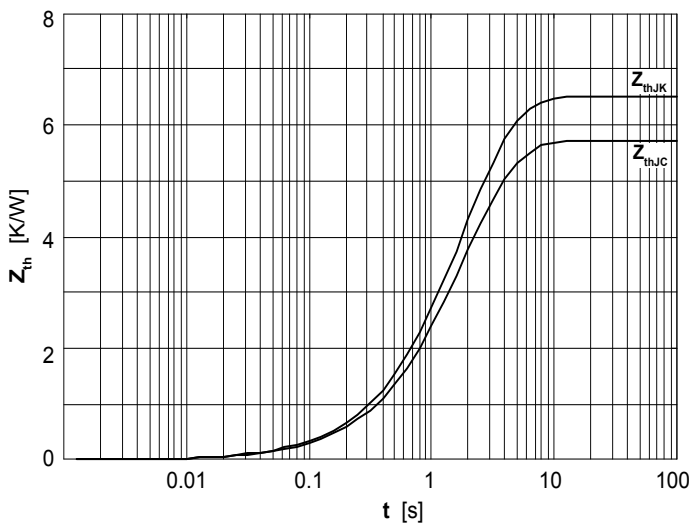


Fig. 6 Transient thermal impedance per diode or thyristor, calculated

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